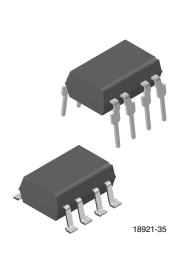
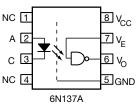


High Speed Optocoupler, 10 MBd







Truth Table (Positive Logic)

	(
LED	ENABLE	OUTPUT			
ON	Н	L			
OFF	Η	Н			
ON	L	Н			
OFF	L	Н			
ON	NC	L			
OFF	NC	Н			

DESCRIPTION

The 6N137A is single channel 10 MBd optocouplers utilizing a high efficient input LED coupled to a very high speed integrated photo-detector logic gate with a strobable output. This detector features an open collector. The internal shield provides a guaranteed common mode transient immunity of 1 kV/ μ s. The use of a 0.1 μ F bypass capacitor connected between pin 5 and 8 is recommended.

AGENCY APPROVALS

(Parts are certified under base model 6N137A)

- UL1577 file number: E52744, double protection
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- CQC GB8898, GB4943.1

FEATURES

- CMR performance of 1 kV/µs
- High speed: 10 MBd typical
- LSTTL/TTL compatibility
- · Low input current capability: 5 mA
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912

Pb-free



RoHS

APPLICATIONS

- Microprocessor system interface
- PLC, ATE input/output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- · AC plasma display panel level shifting
- Multiplexed data transmission
- Digital control power supply
- · Ground loop elimination

ORDERING INFORMATION				
6 N 1 3 PART NUMBER	7 A - X 0 0 # T DIP-8 Option 7 PACKAGE OPTION TAPE AND REEL 7.62 mm			
AGENCY CERTIFIED/PACKAGE	CMR (V/µs)			
UL, cUL, CQC	1000			
DIP-8	6N137A			
SMD-8, option 7	6N137A-X007T			
VDE, UL, cUL, CQC	1000			
DIP-8	6N137A-X001			
SMD-8, option 7	6N137A-X017T			

Note

Additional options may be possible, please contact sales office.



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Average forward current		I _F	20	mA		
Reverse input voltage		V_{R}	5	V		
Enable input voltage		V _E	V _{CC} + 0.5 V	V		
Enable input current		Ι _Ε	5	mA		
Output power dissipation		P _{diss}	35	mW		
OUTPUT						
Supply voltage	1 min maximum	V_{CC}	7	V		
Output current		Io	50	mA		
Output voltage		Vo	7	V		
Output power dissipation		P _{diss}	85	mW		
COUPLER						
Isolation test voltage	t = 1 min	V _{ISO}	5000	V_{RMS}		
Storage temperature		T _{stg}	- 55 to + 125	°C		
Operating temperature		T _{amb}	- 40 to + 85	°C		
Solder reflow temperature (1)	5 s		260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

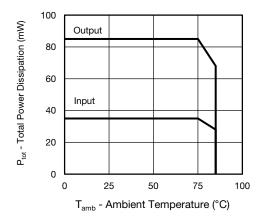


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

RECOMMENDED OPERATING CONDITIONS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT	
Operating temperature		T _{amb}	- 40	85	°C	
Supply voltage		V _{CC}	4.5	5.5	V	
Input current low level		I _{FL}	0	250	μΑ	
Input current high level		I _{FH}	5	15	mA	
Logic high enable voltage		V _{EH}	2	V _{CC}	V	
Logic low enable voltage		V_{EL}	0	0.8	V	
Output pull up resistor		R_L	330	4K	Ω	
Fanout	$R_L = 1 k\Omega$	N		5	-	



PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT					•	•
Input forward voltage	I _F = 10 mA	V _F		1.35	1.7	V
Input forward voltage temperature coefficient	I _F = 10 mA	$\Delta V_F/\Delta T$		- 1.2		mV/K
Input reverse voltage	I _R = 10 μA	BV _R	5			V
Input threshold current	V _E = 2 V, V _{CC} = 5.5 V, I _{OL} (sinking) = 13 mA	I _{TH}		1.8	5	mA
Input capacitance	f = 1 MHz, V _F = 0 V	C _I		28		pF
ОИТРИТ	·					
I Pala la cala caral de caral	$V_E = 0.5 \text{ V}, I_F = 0 \text{ mA}$	Іссн		8	10	mA
High level supply current	$V_E = V_{CC}$, $I_F = 10 \text{ mA}$			5.8		
Law layed ayanby ayarant	$V_E = 0.5 \text{ V, I}_F = 0 \text{ mA}$			10	13	mA
Low level supply current	$V_E = V_{CC}$, $I_F = 10 \text{ mA}$	I _{CCL}		8		mA
High level enable current	V _E = 2 V	I _{EH}		- 0.6	- 1.6	mA
Low level enable current	V _E = 0.5 V	I _{EL}		- 0.9	- 1.6	mA
High level enable voltage		V _{EH}	2			V
Low level enable voltage		V _{EL}			0.8	V
High level output current	$V_E = 2 \text{ V}, V_{CC} = 5.5 \text{ V}, V_O = 5.5 \text{ V}, I_F = 250 \mu\text{A}$	I _{OH}		0.02	100	μΑ
Low level output voltage	$V_E = 2 \text{ V}, V_{CC} = 5.5 \text{ V},$ $I_F = 5 \text{ mA}, I_{OL} \text{ (sinking)} = 13 \text{ mA}$	V _{OL}		0.13	0.60	V
Collector emitter capacitance	f = 1 MHz, T _{amb} = 25 °C	C _{IO}		4		pF
COUPLER						
Coupling capacitance	f = 1 MHz, T _{amb} = 25 °C	C _{IO}		0.9		pF

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay time to high output level	$R_L = 350 \Omega$, $C_L = 15 pF$	t _{PLH}	25	45	75 ⁽¹⁾	ns
Propagation delay time to low output level	$R_L = 350 \Omega, C_L = 15 pF$	t _{PHL}	25	32	75 ⁽¹⁾	ns
Pulse width distortion	$R_L = 350 \Omega, C_L = 15 pF$	t _{PHL} - t _{PLH}		13	35	ns
Propagation delay skew	$R_L = 350 \Omega, C_L = 15 pF$	t _{PSK}		16	40	ns
Output rise time (10 % to 90 %)	$R_L = 350 \Omega, C_L = 15 pF$	t _r		27		ns
Output fall time (90 % to 10 %)	$R_L = 350 \Omega, C_L = 15 pF$	t _f		10		ns
Propagation delay time of enable from V _{EH} to V _{EL}	$R_L = 350 \ \Omega, \ C_L = 15 \ pF, \ V_{EL} = 0 \ V, \ V_{EH} = 3 \ V$	t _{ELH}		47		ns
Propagation delay time of enable from V _{EL} to V _{EH}	$R_L = 350 \Omega, C_L = 15 pF, V_{EL} = 0 V, V_{EH} = 3 V$	t _{EHL}		24		ns

Notes

- Over recommended temperature (T_{amb} = 40 °C to + 85 °C), V_{CC} = 5 V, I_F = 7.5 mA, unless otherwise specified. Typical values applies to V_{CC} = 5 V, T_{amb} = 25 °C
- (1) A JEDEC registered data for 6N137A

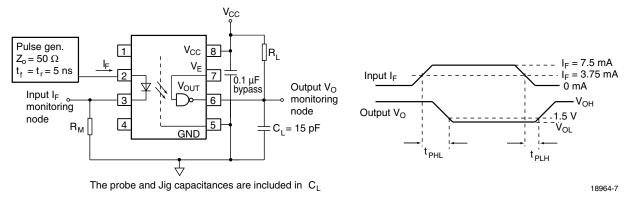


Fig. 2 - Test Circuit for t_{PLH}, t_{PHL}, t_r, and t_f

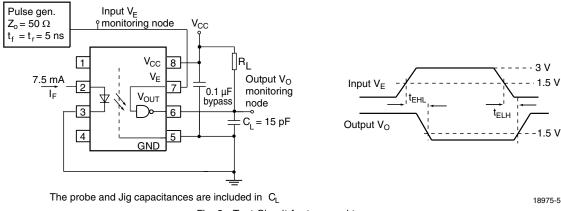


Fig. 3 - Test Circuit for t_{EHL} , and t_{ELH}

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Logic high common mode transient immunity (1)(3)	$ V_{CM} = 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, V_{O(\text{min.})} = 2 \text{ V}, R_L = 350 \Omega, T_{\text{amb}} = 25 ^{\circ}\text{C}$	CM _H	1000			V/µs	
Logic low common mode transient immunity (2)(3)	$ V_{CM} = 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}, V_{O(min.)} = 0 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}C$	CM _L	1000			V/µs	

Notes

- (1) CM_H is the maximum tolerable rate of rise of the common mode voltage to assure that the output will remain in a high logic state (i.e. $V_O > 2.0 \text{ V}$)
- (2) CM_L is the maximum tolerable rate of fall of the common mode voltage to assure that the output will remain in a low logic state (i.e. V_O > 0.8 V)
- (3) No external pull up is required for a high logic state on the enable input. If the enable pin in not used, trying it to V_{CC}.

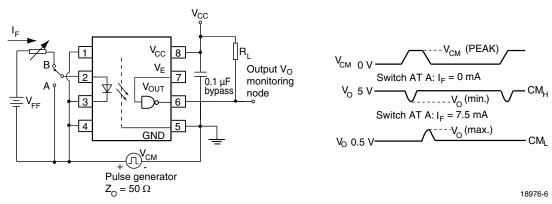


Fig. 4 - Test Circuit for Common Mode Transient Immunity



SAFETY AND INSULATION RATINGS					
PARAMETER		SYMBOL	VALUE	UNIT	
MAXIMUM SAFETY RATINGS					
Output safety power		P _{SO}	600	mW	
Input safety current		I _{si}	230	mA	
Safety temperature		T _S	175	°C	
Comparative tracking index		CTI	175		
INSULATION RATED PARAMETERS					
Maximum withstanding isolation voltage		V _{ISO}	5000	V _{RMS}	
Maximum transient isolation voltage		V _{IOTM}	6000	V_{peak}	
Maxium repetitive peak isolation voltage		V _{IORM}	630	V_{peak}	
Insulation resistance	$T_{amb} = 25 ^{\circ}C$, $V_{DC} = 500 V$	R _{IO}	10 ¹²	Ω	
Isolation resistance	$T_{amb} = 100 ^{\circ}C, V_{DC} = 500 V$	R _{IO}	10 ¹¹	Ω	
Climatic classification (according to IEC 68 part 1)			40/85/21		
Environment (pollution degree in accordance to	to DIN VDE 0109)		2		
Maximum creepage			7	mm	
Clearance			7	mm	
Insulation thickness			0.4	mm	

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

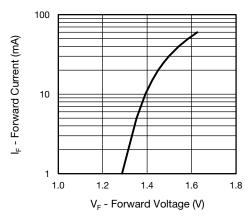


Fig. 5 - Diode Forward Current vs. Forward Voltage

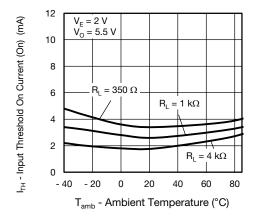


Fig. 6 - Input Threshold On Current vs. Ambient Temperature

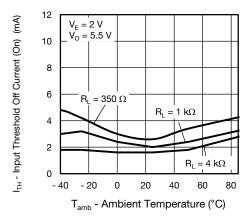


Fig. 7 - Input Threshold Off Current vs. Ambient Temperature

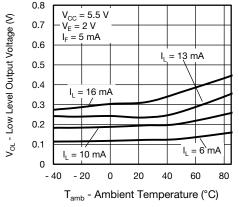


Fig. 8 - Low Level Output Voltage vs. Ambient Temperature

[•] As per DIN EN 60747-5-5, §7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of prodective circuits.



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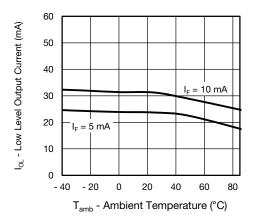


Fig. 9 - Low Level Output Current vs. Ambient Temperature

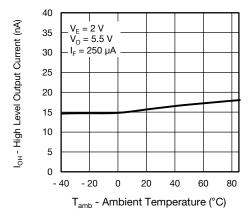


Fig. 10 - High Level Output Current vs. Ambient Temperature

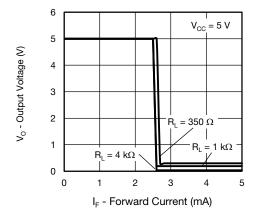


Fig. 11 - Output Voltage vs. Diode Forward Current

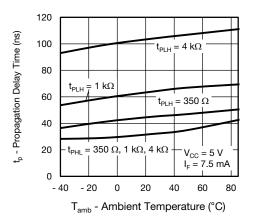


Fig. 12 - Propagation Delay Time vs. Ambient Temperature

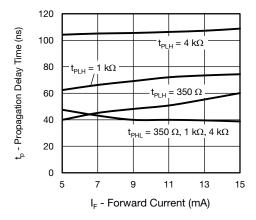


Fig. 13 - Propagation Delay Time vs. Diode Forward Current

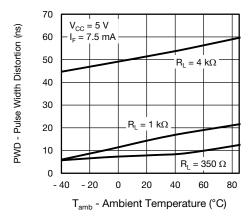


Fig. 14 - Pulse Width Distortion vs. Ambient Temperature



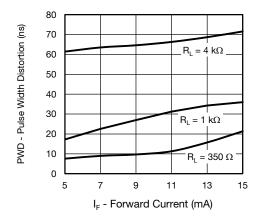


Fig. 15 - Pulse Width Distortion vs. Diode Input Current

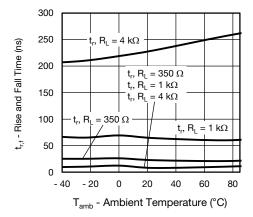


Fig. 16 - Rise And Fall Time vs. Ambient Temperature

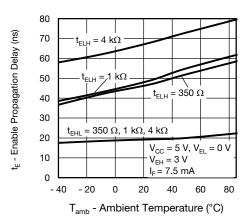


Fig. 17 - Enable Propagation Delay vs. Ambient Temperature

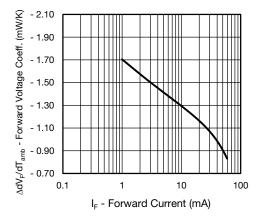
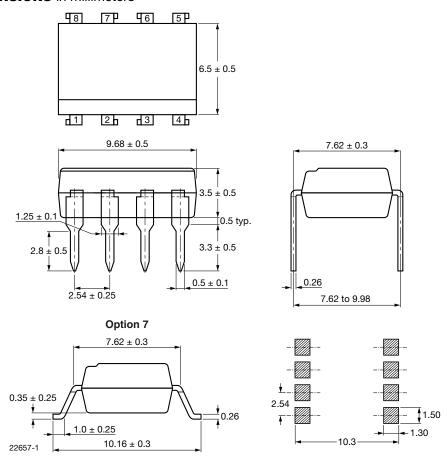
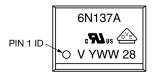


Fig. 18 - Forward Voltage Coefficient vs. Forward Current

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.

PACKING INFORMATION

DEVICE PER TUBE OR REEL					
UNITS/TUBE	TUBES/BOX	UNITS/BOX			
50	40	2000			

TAPE AND REEL PACKAGING FOR OPTION 7 (dimensions in millimeters)

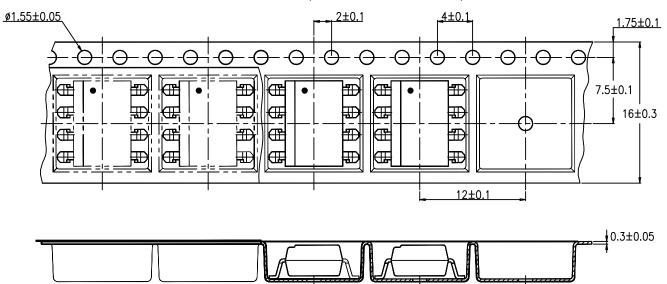


Fig. 19 - Reel Dimensions (1000 units per reel)



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Vishay

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Revision: 02-Oct-12 Document Number: 91000